

# NPN POWER DARLINGTON TRANSISTOR ARRAY



Designed for high power switching applications, hammer drive, pulse motor drive and inductive load drive applications.

#### Features:

- High reliability small-sized available (3 in 1)
- Epoxy single-inline package (8 pin)
- High collector power dissipation: PD = 3W @ TA = 25°C (Three device action)
- High collector current: IC = 5A (Max.)
- High DC current gain: hFE = 1000 (Min.) @ VCE = 3V, IC = 3A



## maximum ratings ( $T_A = 25^{\circ}C$ ) (unless otherwise specified)

ARRAY CONFIGURATION

RATING	SYMBOL	D74A5D	UNITS
Collector-Emitter Voltage	V <sub>CEO</sub>	100	Volts
Collector-Base Voltage	V <sub>CBO</sub>	100	Volts
Emitter Base Voltage	V <sub>EBO</sub>	5	Volts
Collector Current — Continuous Peak	I <sub>C</sub> I <sub>CM</sub>	5 8	A
Base Current — Continuous	IB	0.1	A
Collector Power Dissipation (One Device Action, T <sub>A</sub> = 25°C)	PD	1.8	Watts
Collector Power Dissipation (Three Device Action, T <sub>A</sub> = 25°C)	PD	3.0	Watts
Operating and Storage Junction Temperature Range	TJ, TSTG	-55 to +150	°C

#### thermal characteristics

Thermal Resistance, Junction to Ambient	Σ R <sub>θJA</sub>	41.7	°C/W
Maximum Lead Temperature for Soldering Purpose: 1/4" from Case for 5 Seconds	TL	260	°C

### electrical characteristics ( $T_A = 25^{\circ}C$ ) (unless otherwise specified)

CHARACTERISTIC	SYMBOL	MIN	ТҮР	MAX	UNIT
CHARACTERISTICSYMBOLMINTYPMAXOff characteristicsCollector-Emitter Breakdown Voltage $(I_C = 30mA, I_B = 0)$ VBR(CEO)100Collector Cutoff Current $(V_{CE} = 50V, I_B = 0)$ ICEO0.5Collector Cutoff Current $(V_{CB} = 100V, I_E = 0)$ ICBO200Emitter Cutoff Current $(V_{EB} = 5V, I_C = 0)$ IEBO2On characteristics					
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 30mA, I <sub>B</sub> = 0)	V <sub>BR(CEO)</sub>	100	_		Volts
Collector Cutoff Current (V <sub>CE</sub> = 50V, I <sub>B</sub> = 0)	ICEO			0.5	mA
Collector Cutoff Current (V <sub>CB</sub> = 100V, I <sub>E</sub> = 0)	Ісво		_	200	μΑ
Emitter Cutoff Current (V <sub>EB</sub> = 5V, I <sub>C</sub> = 0)	I <sub>EBO</sub>			2	mA
on characteristics					
DC Current Gain $(I_C = 0.5A, V_{CE} = 3V)$ $(I_C = 3A, V_{CE} = 3V)$	h <sub>FE</sub>	1000 1000	_	-	_

Collector-Emitter Saturation Voltage (I <sub>C</sub> = 3A, I <sub>B</sub> = 12mA) (I <sub>C</sub> = 5A, I <sub>B</sub> = 20mA)	V <sub>CE(sat)</sub>	 	2 4	Volts
Base-Emitter Voltage (V <sub>CE</sub> = 3V, I <sub>C</sub> = 3A)	V <sub>BE(on)</sub>	 	2.5	Volts

### switching characteristics

Turn-on Time	I <sub>C</sub> = 3A, I <sub>B1</sub> = -I <sub>B2</sub> = 12mA	t <sub>on</sub>	 1.5		μs
Turn-off Time	$V_{BE(off)} = 5V, R_{L} = 10\Omega$	t <sub>f</sub>	 8.5	-	